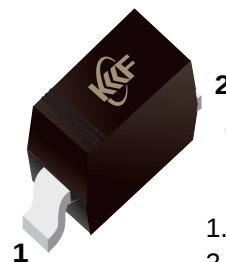


1N4148W

Switching Diodes

Features

- For surface mounted applications
- Glass Passivated Chip Junction
- Fast reverse recovery time
- Ideal for automated placement



1.Cathode
2.Anode

Simplified outline(SOD-123)



Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbols	1N4148W	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	100	V
Maximum RMS voltage	V_{RMS}	75	V
Continuous Forward Current	I_F	300	mA
Non-repetitive Peak Forward Surge Current at 1ms	I_{FSM}	4	A
Total Power Dissipation	P_{tot}	400	mW
Operating and Storage Temperature Range	T_j, T_{stg}	-55 ~ +150	$^\circ\text{C}$

Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbols	1N4148W	Units
Reverse Breakdown Voltage at $I_R=1\mu\text{A}$	$V_{(BR)R}$	75	V
Maximum Forward Voltage at 1 mA at 10 mA at 50 mA at 150 mA	V_F	0.715 0.855 1.00 1.25	V
Peak Reverse Current at $V_R=20\text{V}$ $T_j=25^\circ\text{C}$ at $V_R=75\text{V}$ $T_j=25^\circ\text{C}$ at $V_R=25\text{V}$ $T_j=150^\circ\text{C}$ at $V_R=75\text{V}$ $T_j=150^\circ\text{C}$	I_R	0.025 1 30 50	μA
Typical Junction Capacitance	C_j	5	pF
Maximum Reverse Recovery Time	t_{rr} Typical	8	ns

1N4148W

Fig.1 Forward Current Derating Curve

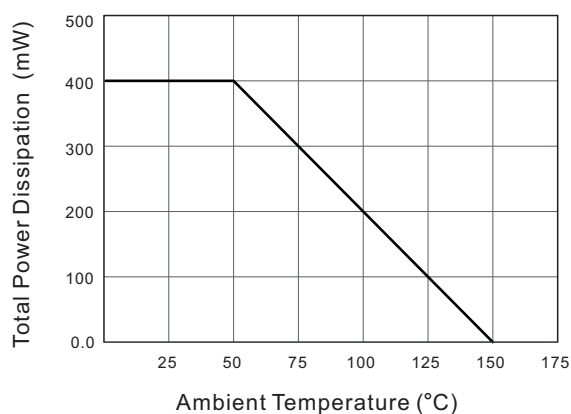


Fig.2 Typical Reverse Characteristics

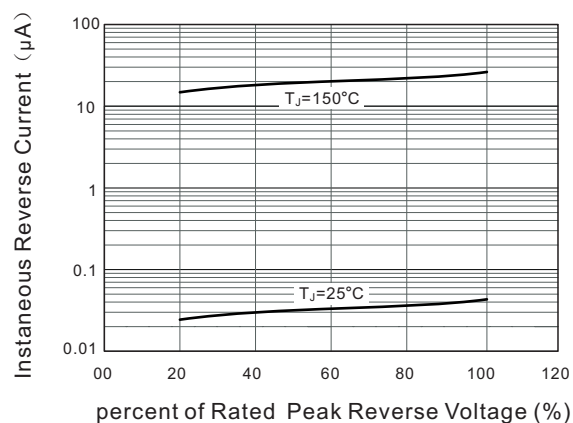


Fig.3 Typical Instantaneous Forward Characteristics

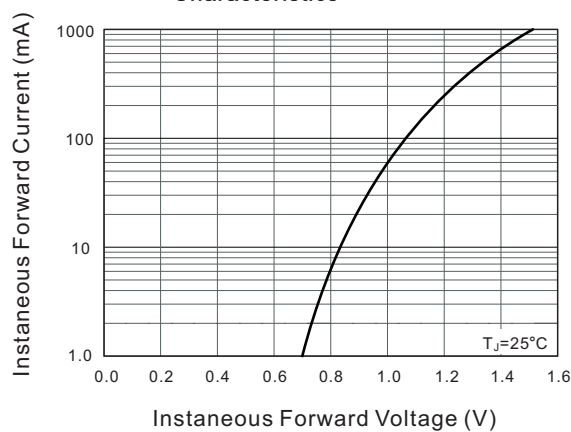
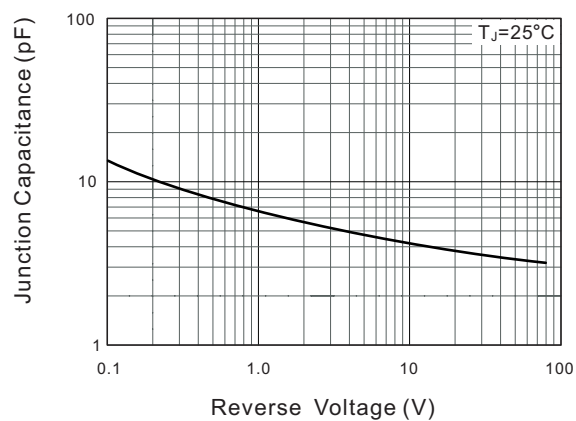
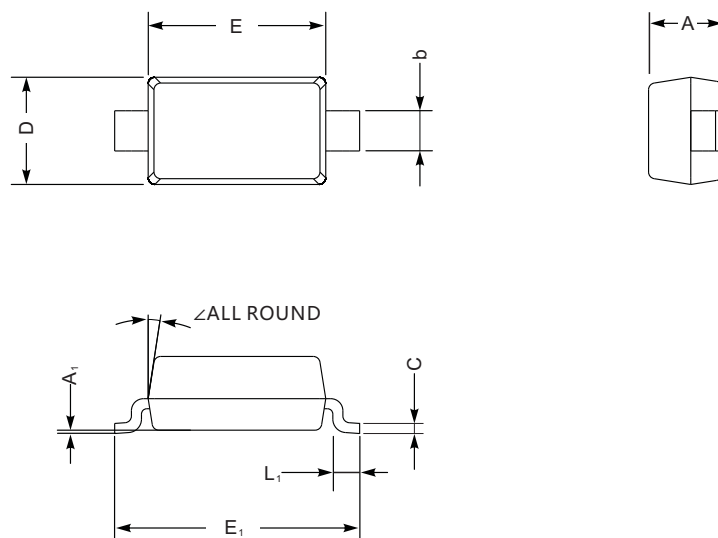


Fig.4 Typical Junction Capacitance



■ SOD-123



SOD-123 mechanical data

UNIT		A	C	D	E	E ₁	L ₁	b	A ₁	∠
mm	max	1.3	0.22	1.8	2.8	3.9	0.45	0.7	0.2	9°
	min	0.9	0.09	1.5	2.5	3.6	0.25	0.5	—	
mil	max	51	8.7	71	110	154	18	28	8	
	min	35	3.5	59	98	142	10	20	—	

■ The recommended mounting pad size

